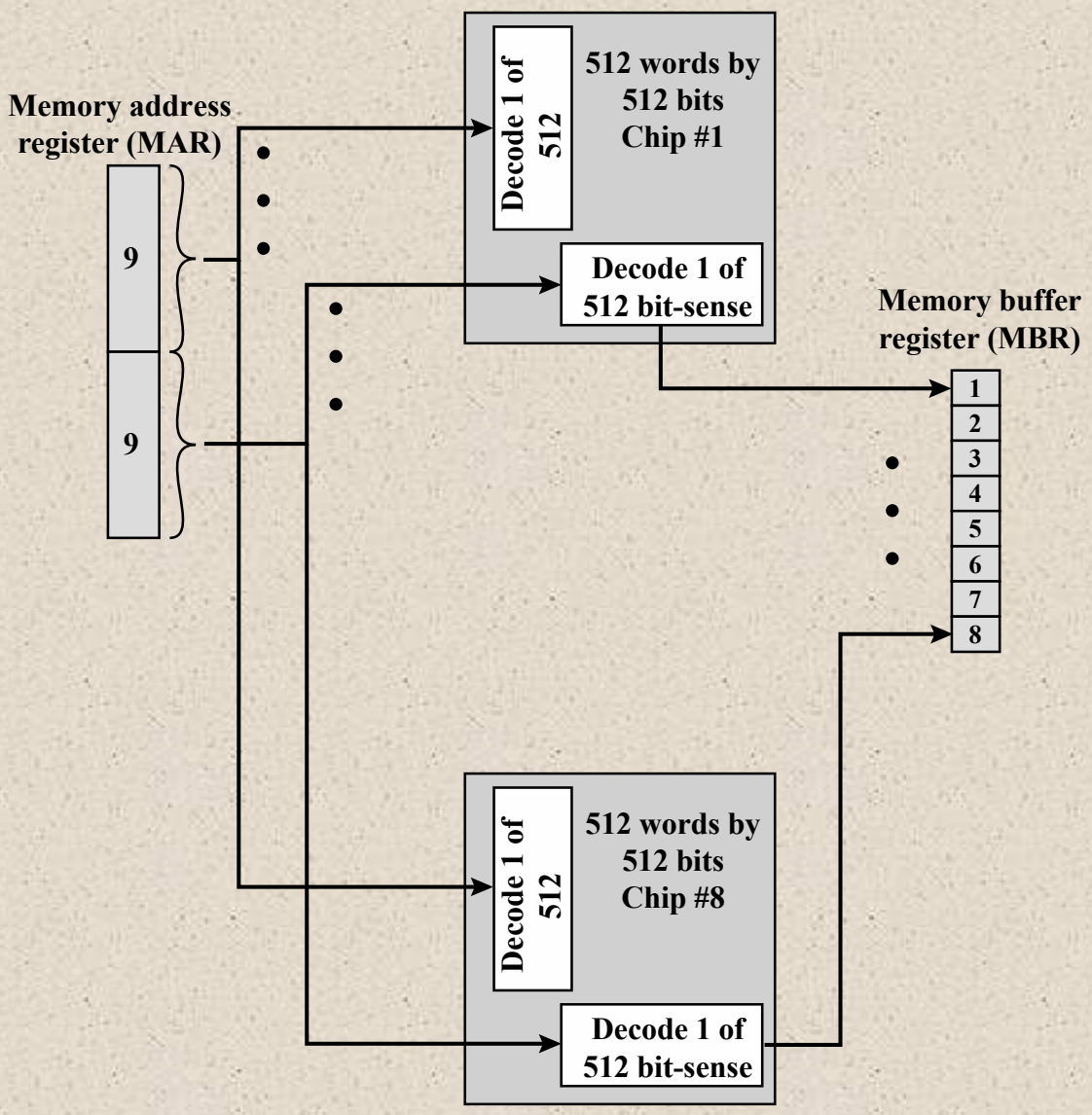

Figure 5.5 256-KByte Memory Organization

Advanced DRAM Organization

- One of the most critical system bottlenecks when using high-performance processors is the interface to main internal memory
- The traditional DRAM chip is constrained both by its internal architecture and by its interface to the processor's memory bus
- A number of enhancements to the basic DRAM architecture have been explored
  - The schemes that currently dominate the market are SDRAM and DDR-DRAM

Synchronous DRAM (SDRAM)

One of the most widely used forms of DRAM

Exchanges data with the processor synchronized to an external clock signal and running at the full speed of the processor/memory bus without imposing wait states

With synchronous access the DRAM moves data in and out under control of the system clock

- The processor or other master issues the instruction and address information which is latched by the DRAM
- The DRAM then responds after a set number of clock cycles
- Meanwhile the master can safely do other tasks while the SDRAM is processing

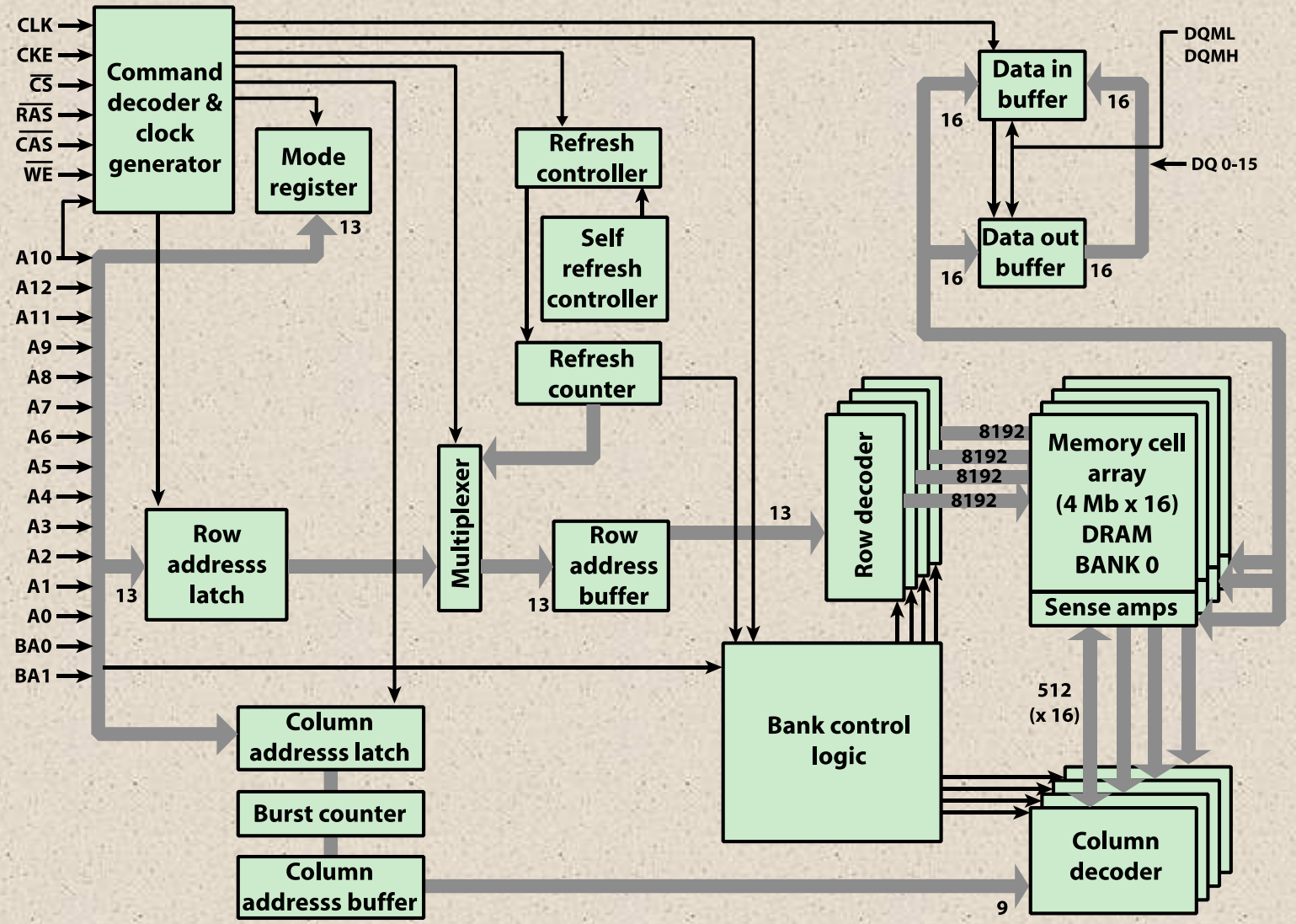

Figure 5.12 256-Mb Synchronous Dynamic RAM (SDRAM)

Double Data Rate SDRAM (DDR SDRAM)

- Developed by the JEDEC Solid State Technology Association (Electronic Industries Alliance's semiconductor-engineering-standardization body)
- Numerous companies make DDR chips, which are widely used in desktop computers and servers
- DDR achieves higher data rates in three ways:
  - First, the data transfer is synchronized to both the rising and falling edge of the clock, rather than just the rising edge
  - Second, DDR uses higher clock rate on the bus to increase the transfer rate
  - Third, a buffering scheme is used

	DDR1	DDR2	DDR3	DDR4
Prefetch buffer (bits)	2	4	8	8
Voltage level (V)	2.5	1.8	1.5	1.2
Front side bus data rates (Mbps)	200—400	400—1066	800—2133	2133—4266

Table 5.4
DDR Characteristics

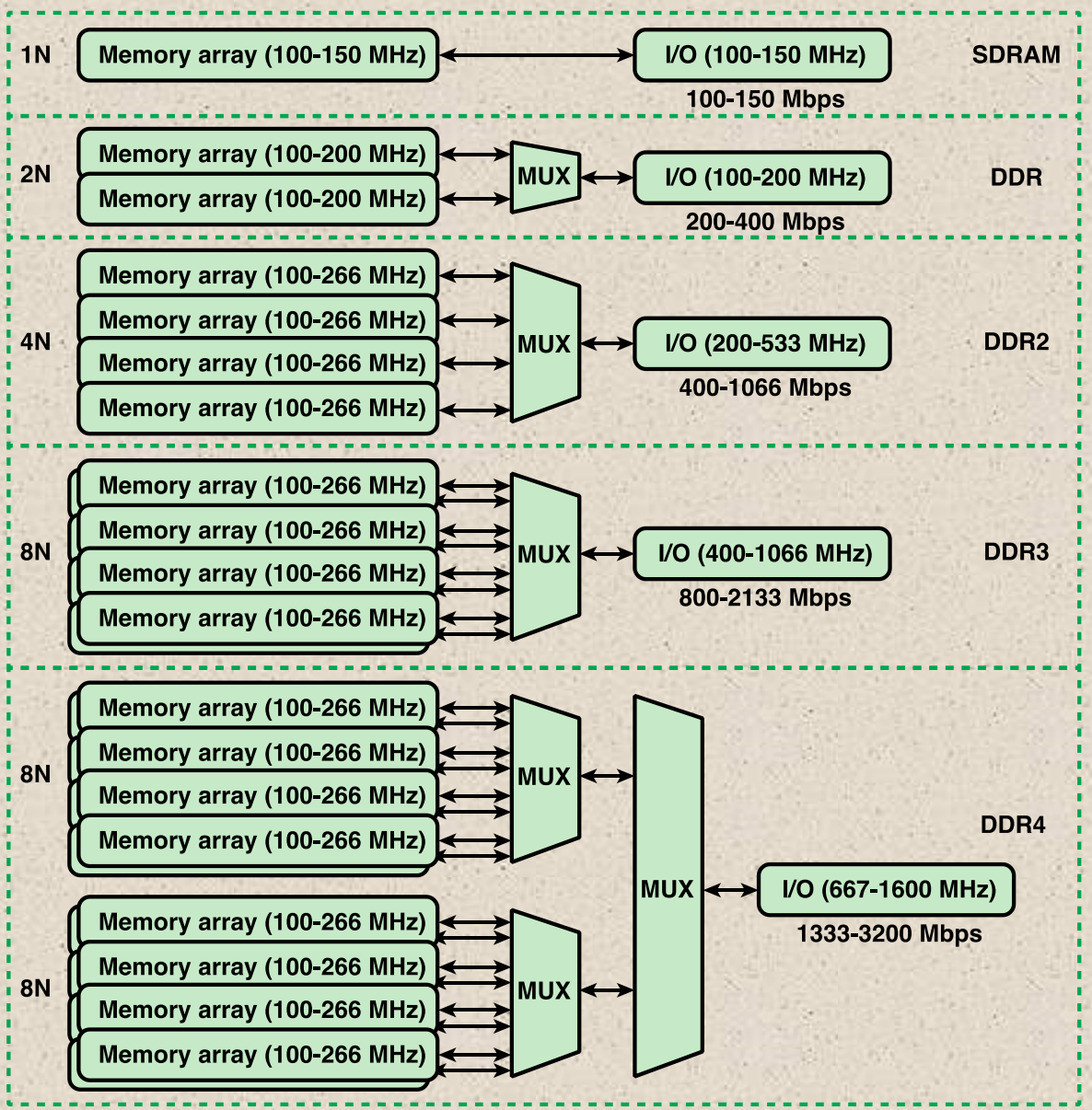

Figure 5.14 DDR Generations